

SHINDENG

General Purpose Rectifiers

SIL Bridges

D2SB80

800V 1.5A

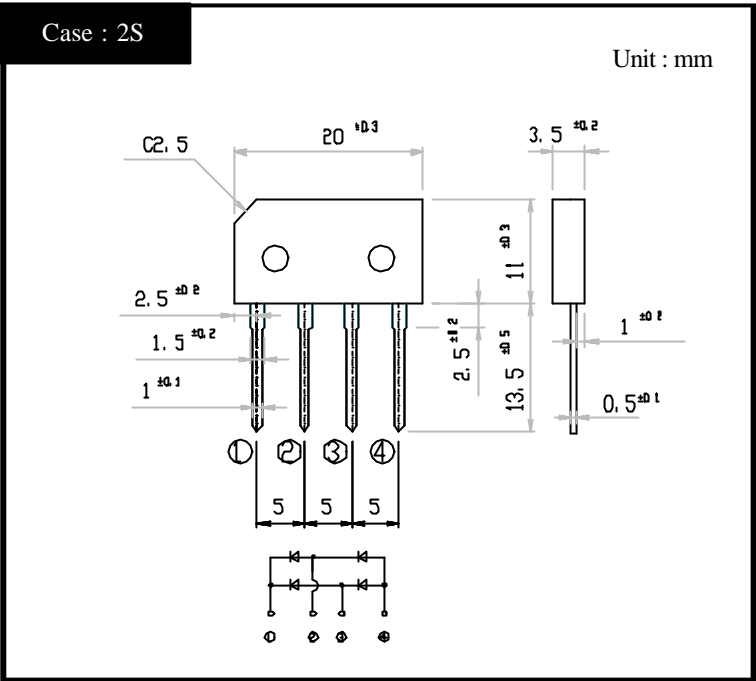
FEATURES

Thin Single In-Line Package
High IFSM
Applicable to Automatic Insertion

APPLICATION

Switching power supply
Home Appliances, Office Equipment
Telecommunication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings (If not specified Tl=25)

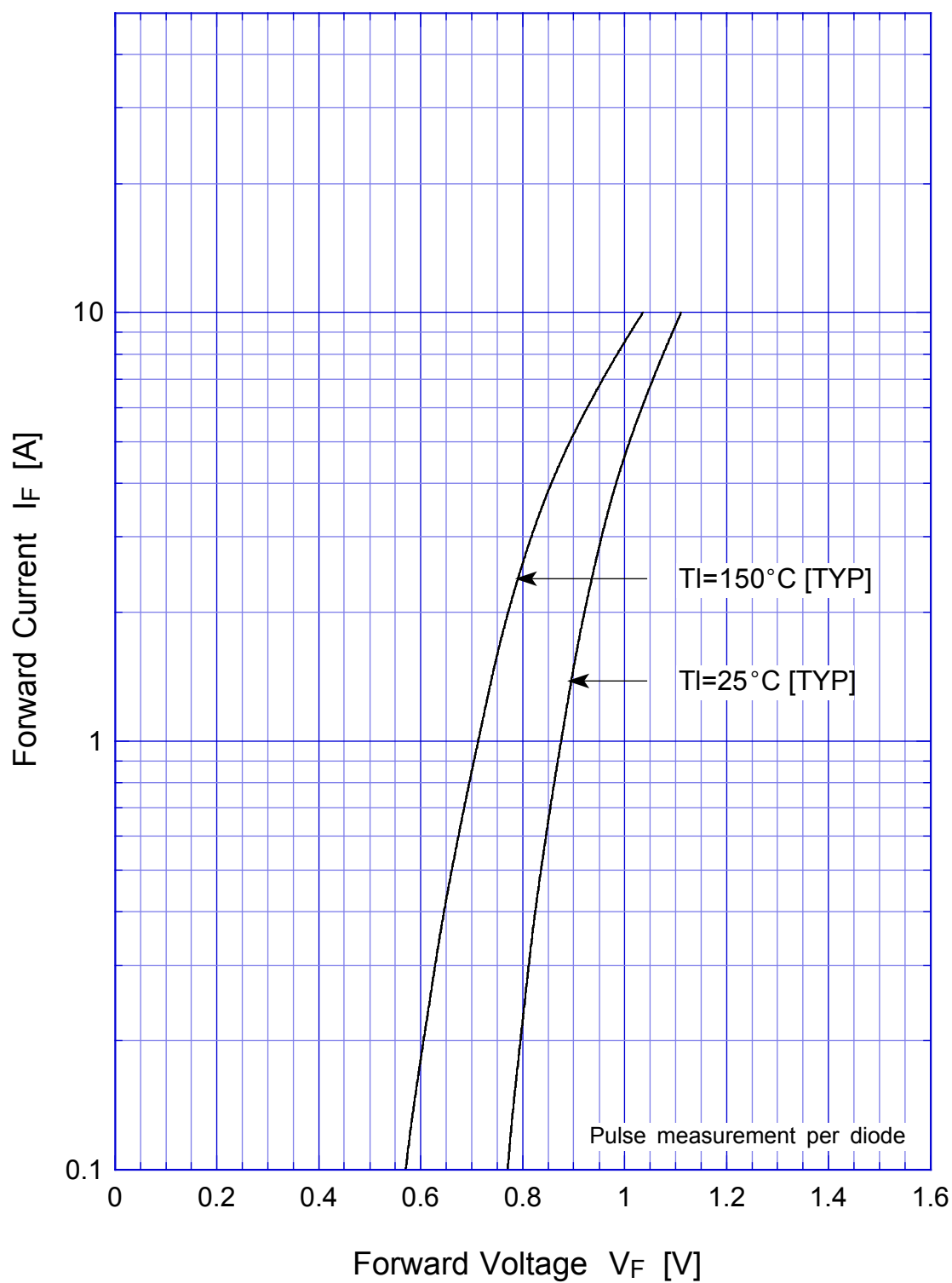
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40 ~ 150	
Operating Junction Temperature	Tj		150	
Maximum Reverse Voltage	V _{RM}		800	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate, Ta=25	1.5	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Tj=25	80	A
Current Squared Time	I ² t	2ms t < 10ms Tj=25	32	A ² s

Electrical Characteristics (If not specified Tl=25)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	If=0.75A, Pulse measurement,Rating of per diode	Max.1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement,Rating of per diode	Max.10	μ A
Thermal Resistance	jl	junction to lead	Max.10	/W
	ja	junction to ambient	Max.47	

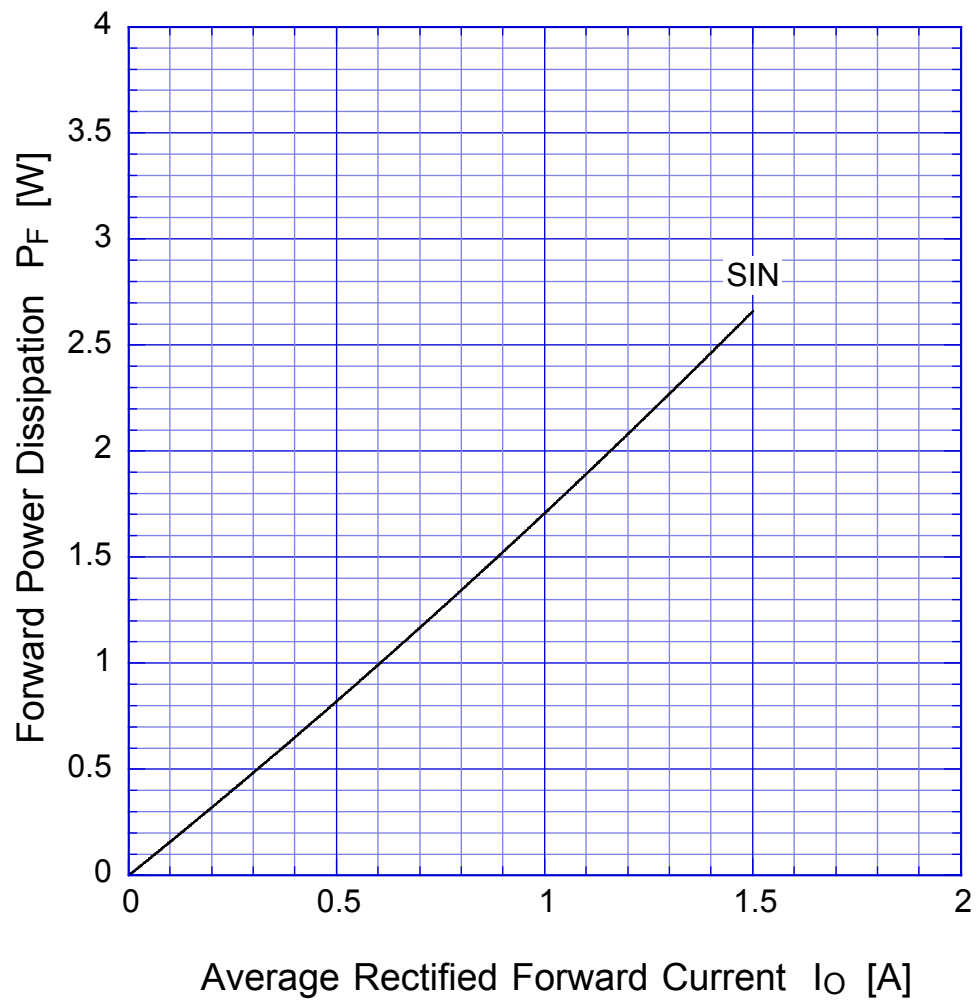
D2SBx

Forward Voltage



D2SBx

Forward Power Dissipation

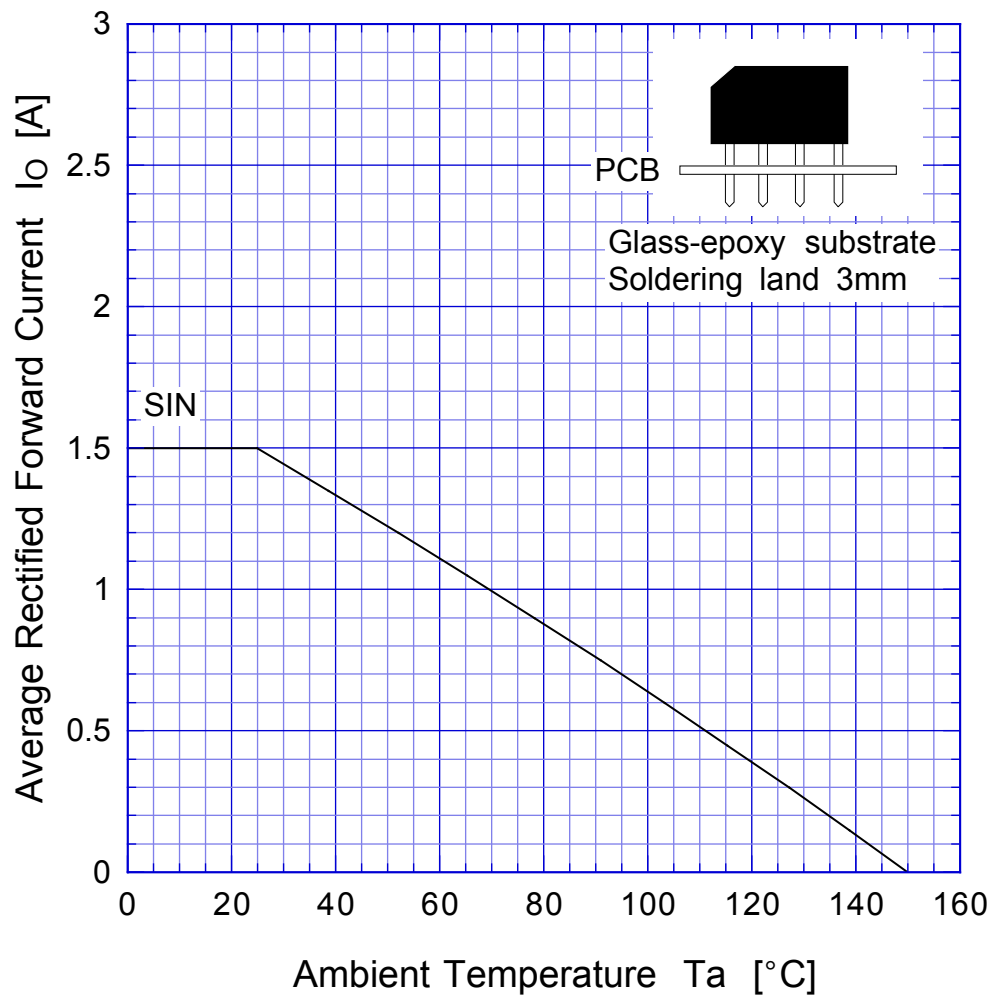


$T_j = 150^\circ\text{C}$

Sine wave

D2SBx

Derating Curve



Sine wave
R-load
Free in air

D2SBx

Peak Surge Forward Capability

